

BT151X series

Thyristors

Rev. 5 — 1 November 2011

Product data sheet

1. Product profile

1.1 General description

Passivated thyristors in a SOT186A full pack plastic package.

1.2 Features and benefits

- High thermal cycling performance
- High bidirectional blocking voltage capability
- Isolated mounting base.

1.3 Applications

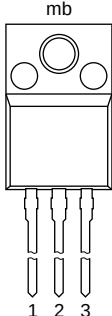
- Motor control
- Industrial and domestic lighting, heating and static switching.

1.4 Quick reference data

- $V_{\text{DRM}}, V_{\text{RRM}} \leq 800 \text{ V}$ (BT151X-800)
- $V_{\text{DRM}}, V_{\text{RRM}} \leq 650 \text{ V}$ (BT151X-650)
- $V_{\text{DRM}}, V_{\text{RRM}} \leq 500 \text{ V}$ (BT151X-500)
- $I_{\text{T(RMS)}} \leq 12 \text{ A}$
- $I_{\text{T(AV)}} \leq 7.5 \text{ A}$
- $I_{\text{TSM}} \leq 120 \text{ A}$.

2. Pinning information

Table 1. Discrete pinning

Pin	Description	Simplified outline	Symbol
1	cathode (K)		
2	anode (A)		
3	gate (G)		
mb	mounting base; isolated		

SOT186A (TO-220)



3. Ordering information

Table 2. Ordering information

Type number	Package		
	Name	Description	Version
BT151X-500	-	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3 lead TO-220 'full pack'	SOT186A
BT151X-650			
BT151X-800			

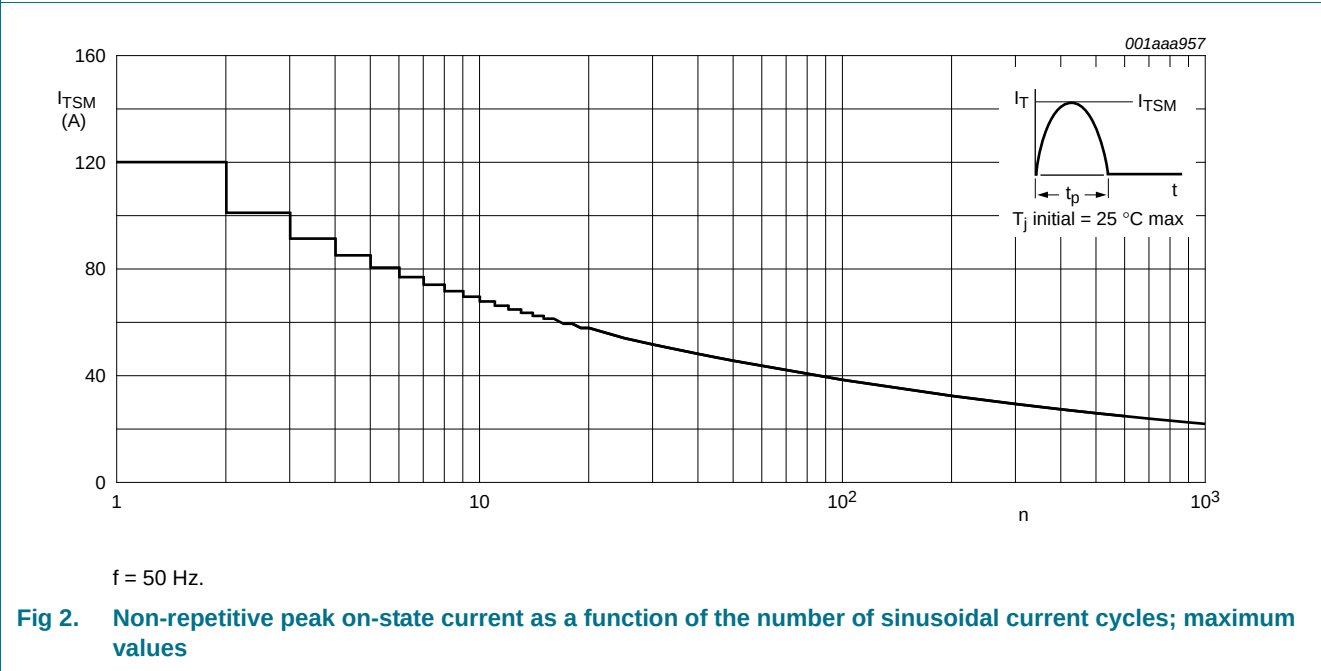
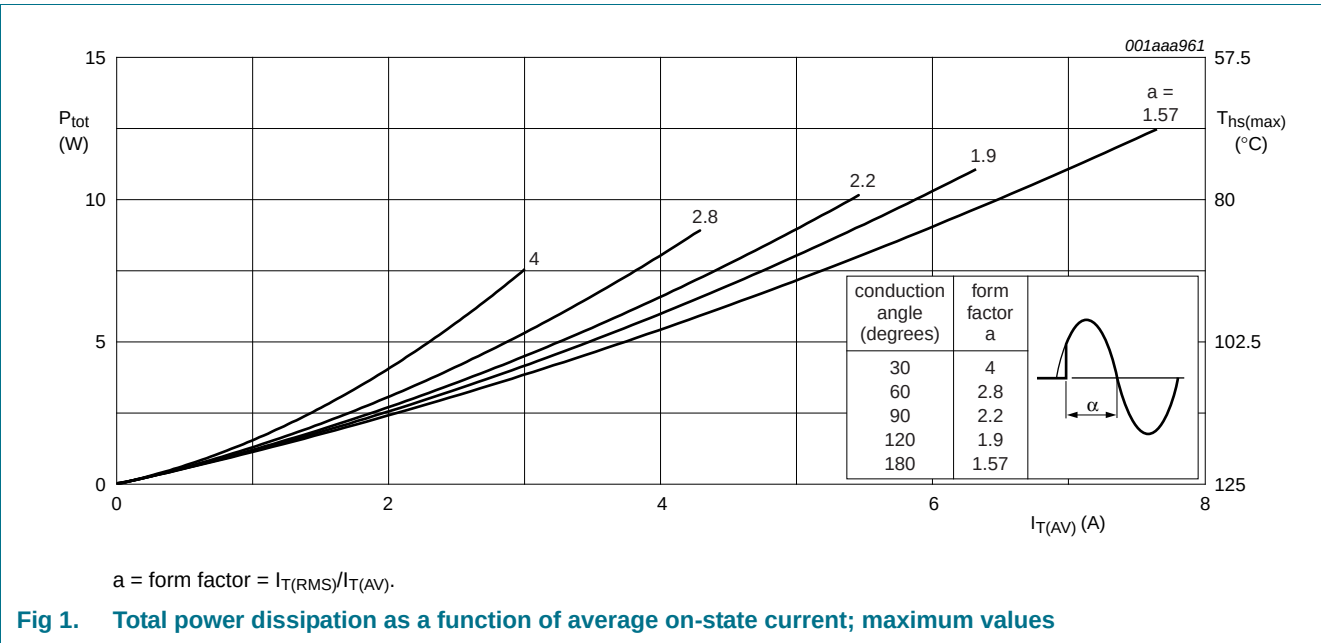
4. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM} , V_{RRM}	repetitive peak off-state voltage				
	BT151X-500	[1]	-	500	V
	BT151X-650	[1]	-	650	V
	BT151X-800		-	800	V
$I_{T(AV)}$	average on-state current	half sinewave; $T_{hs} \leq 69\text{ °C}$; Figure 1	-	7.5	A
$I_{T(RMS)}$	RMS on-state current	all conduction angles; Figure 4 and Figure 5	-	12	A
I_{TSM}	non-repetitive peak on-state current	half sinewave; $T_j = 25\text{ °C}$ prior to surge; Figure 2 and Figure 3			
		$t = 10\text{ ms}$	-	120	A
		$t = 8.3\text{ ms}$	-	132	A
I^2t	I^2t for fusing	$t = 10\text{ ms}$	-	72	A ² s
di_T/dt	repetitive rate of rise of on-state current after triggering	$I_{TM} = 20\text{ A}$; $I_G = 50\text{ mA}$; $di_G/dt\ 50\text{ mA}/\mu\text{s}$	-	50	A/ μs
I_{GM}	peak gate current		-	2	A
V_{RGM}	peak reverse gate voltage		-	5	V
P_{GM}	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T_{stg}	storage temperature		-40	+150	°C
T_j	junction temperature		-	125	°C

- [1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/ μs .



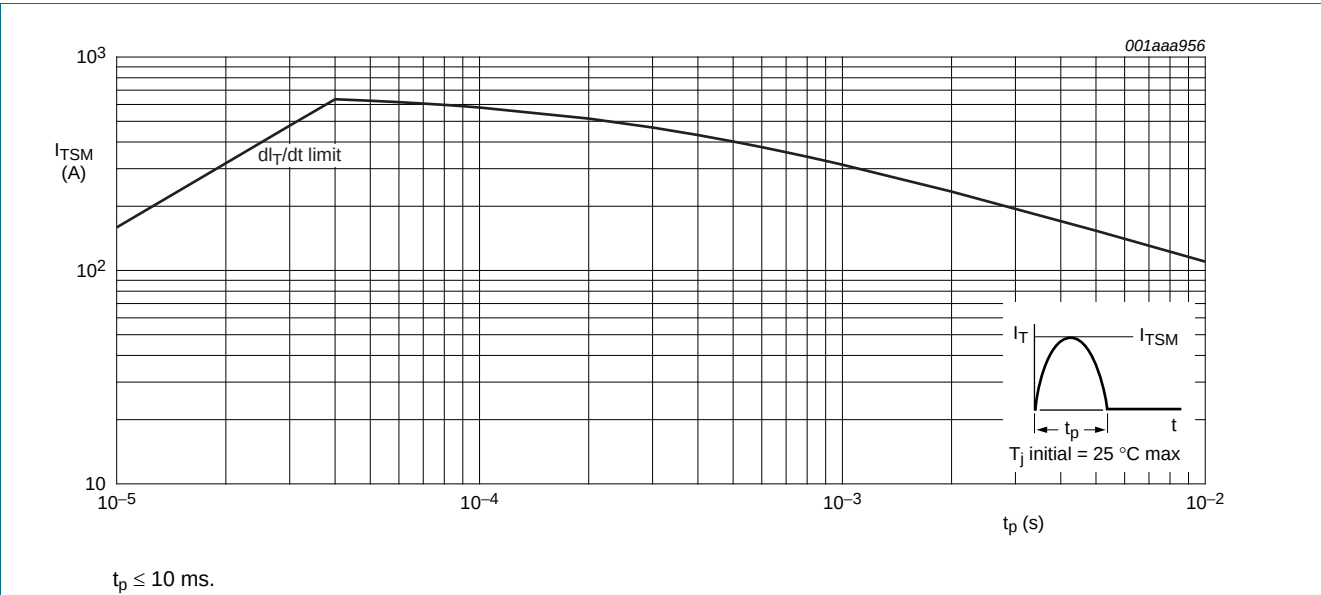


Fig 3. Non-repetitive peak on-state current as a function of pulse width; maximum values

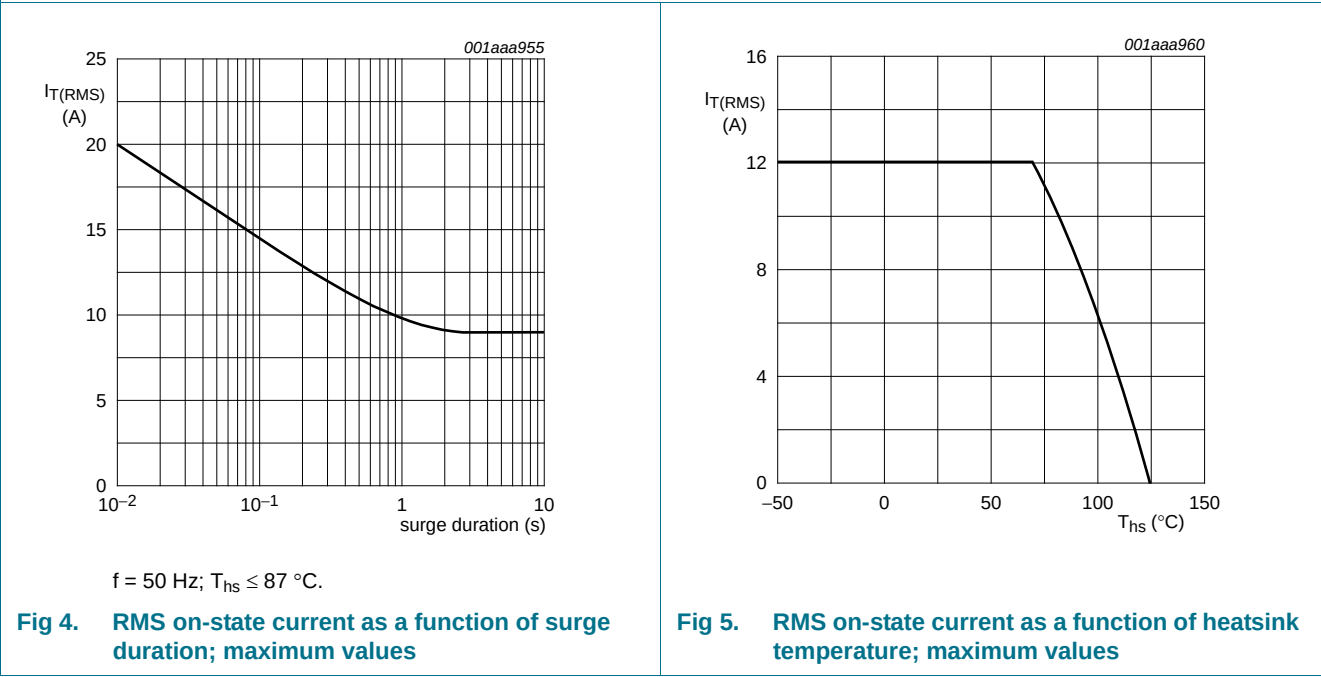


Fig 4. RMS on-state current as a function of surge duration; maximum values

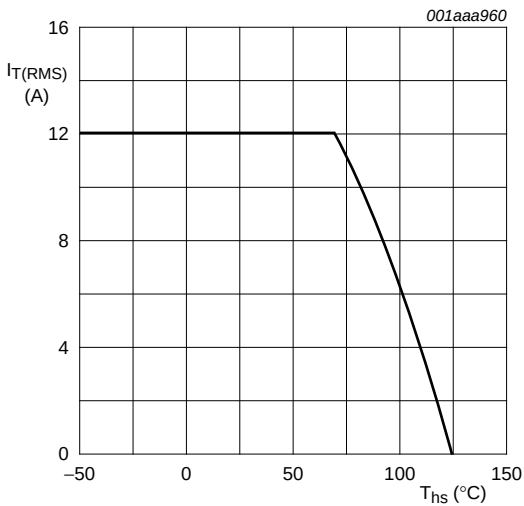
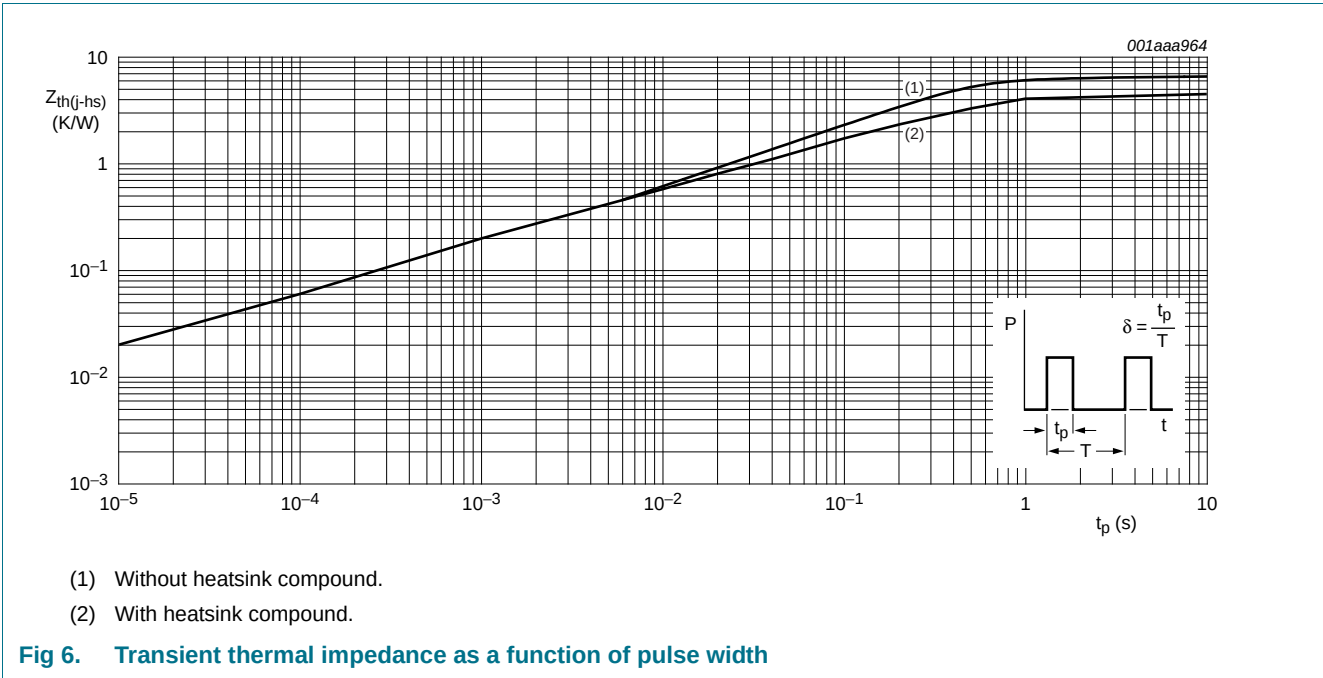


Fig 5. RMS on-state current as a function of heatsink temperature; maximum values

5. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Max	Unit
$R_{th(j-hs)}$	thermal resistance from junction to heatsink	Figure 6 with heatsink compound	-	4.5	K/W
		without heatsink compound	-	6.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	55	-	K/W



6. Isolation characteristics

Table 5. Isolation limiting values and characteristics

$T_{hs} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified

Symbol	Parameter	Conditions	Typ	Max	Unit
V_{isol}	RMS isolation voltage from all three terminals to external heatsink	$f = 50$ to 60 Hz ; sinusoidal waveform; R.H. $\leq 65\%$; clean and dust free	-	2500	V
C_{isol}	capacitance from pin 2 to external heatsink	$f = 1\text{ MHz}$	10	-	pF

7. Characteristics

Table 6. Characteristics

$T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise stated

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
I_{GT}	gate trigger current	$V_D = 12\text{ V}$; $I_T = 0.1\text{ A}$; Figure 8	-	2	15	mA
I_L	latching current	$V_D = 12\text{ V}$; $I_{GT} = 0.1\text{ A}$; Figure 10	-	10	40	mA
I_H	holding current	$V_D = 12\text{ V}$; $I_{GT} = 0.1\text{ A}$; Figure 11	-	7	20	mA
V_T	on-state voltage	$I_T = 23\text{ A}$; Figure 9	-	1.4	1.75	V
V_{GT}	gate trigger voltage	$V_D = 12\text{ V}$; $I_T = 0.1\text{ A}$; Figure 7	-	0.6	1.5	V
		$V_D = V_{DRM(max)}$; $I_T = 0.1\text{ A}$; $T_j = 125\text{ }^{\circ}\text{C}$	0.25	0.4	-	V
I_D, I_R	off-state leakage current	$V_D = V_{DRM(max)}$; $V_R = V_{RRM(max)}$; $T_j = 125\text{ }^{\circ}\text{C}$	-	0.1	0.5	mA
Dynamic characteristics						
dV_D/dt	critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}$; $T_j = 125\text{ }^{\circ}\text{C}$; exponential waveform; Figure 12				
		gate open circuit	50	130	-	V/ μs
		$R_{GK} = 100\text{ }\Omega$	200	1000	-	V/ μs
t_{gt}	gate controlled turn-on time	$I_{TM} = 40\text{ A}$; $V_D = V_{DRM(max)}$; $I_G = 0.1\text{ A}$; $dI_G/dt = 5\text{ A}/\mu\text{s}$	-	2	-	μs
t_q	circuit commuted turn-on time	$V_D = 67\% V_{DRM(max)}$; $T_j = 125\text{ }^{\circ}\text{C}$; $I_{TM} = 20\text{ A}$; $V_R = 25\text{ V}$; $dI_{TM}/dt = 30\text{ A}/\mu\text{s}$; $dV_D/dt = 50\text{ V}/\mu\text{s}$; $R_{GK} = 100\text{ }\Omega$	-	70	-	μs

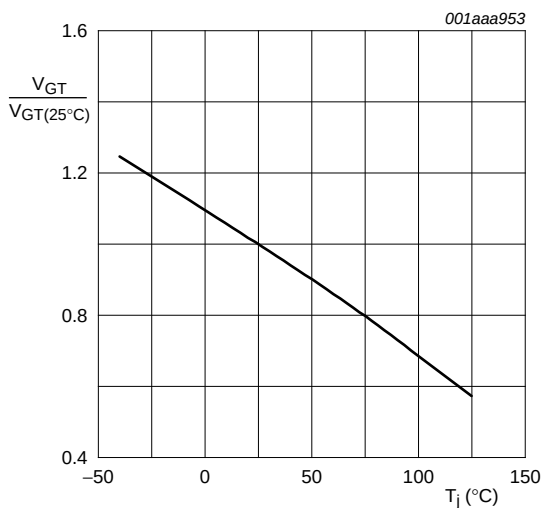


Fig 7. Normalized gate trigger voltage as a function of junction temperature

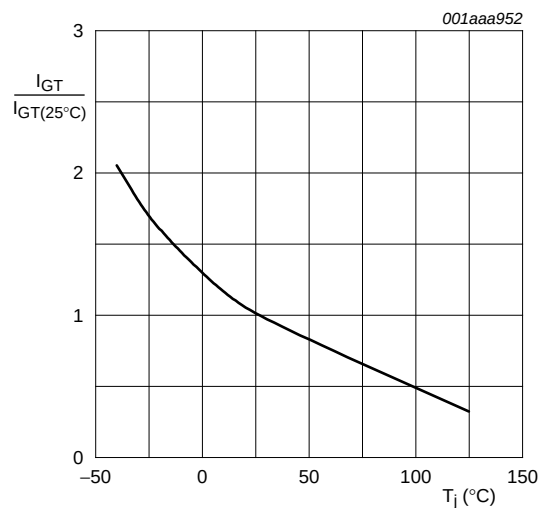
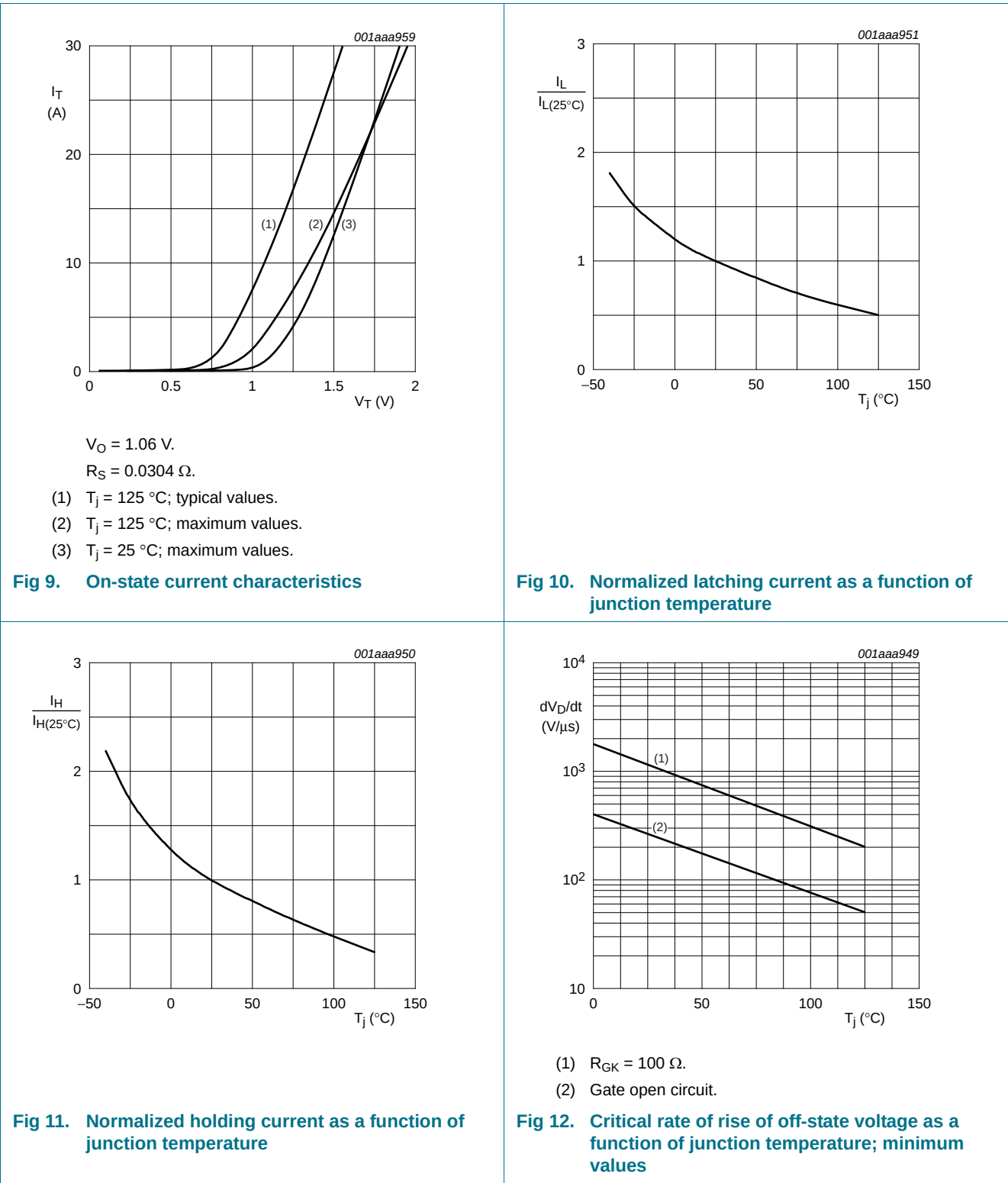


Fig 8. Normalized gate trigger current as a function of junction temperature



8. Package information

Epoxy meets requirements of UL94 V-0 at 1/8 inch.

9. Package outline

Plastic single-ended package; isolated heatsink mounted;
1 mounting hole; 3-lead TO-220 'full pack'

SOT186A

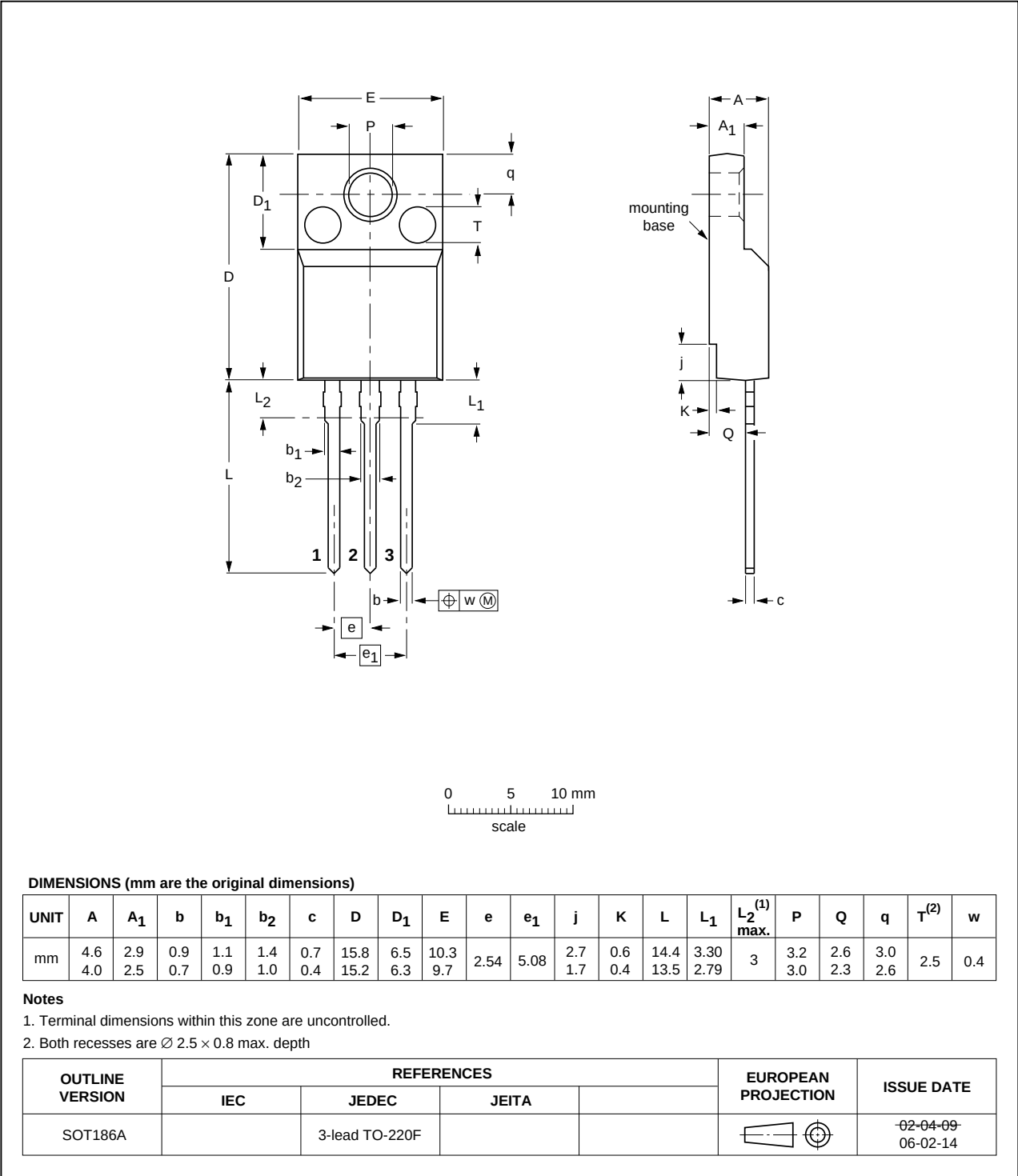


Fig 13. Package outline SOT186A (TO-220)

10. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BT151X_SER v.5	20111101	Product data sheet		BT151X_SERIES v.4
Modifications:	- The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. - Legal texts have been adapted to the new company name where appropriate.			
BT151X_SERIES v.4	20040609	Product data sheet		BT151X_SERIES v.3
BT151X_SERIES v.3	20030901	Product specification		BT151X_SERIES v.2
BT151X_SERIES v.2	19990601	Product specification		BT151X_SERIES v.1
BT151X_SERIES v.1	19970901	Product specification		-

11. Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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13. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	1
3	Ordering information	2
4	Limiting values	2
5	Thermal characteristics	5
6	Isolation characteristics	5
7	Characteristics	6
8	Package information	7
9	Package outline	8
10	Revision history	9
11	Legal information	10
11.1	Data sheet status	10
11.2	Definitions	10
11.3	Disclaimers	10
11.4	Trademarks	11
12	Contact information	11
13	Contents	12

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